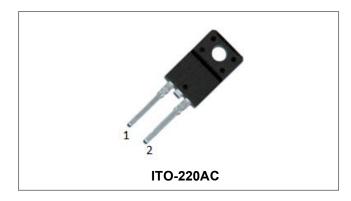






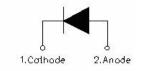
## **SDURF2040 ULTRAFAST RECTIFIER**



## **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## **Circuit Diagram**



### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Maximum Ratings(at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	400	V
Average Rectified Forward Current In DC	I <sub>F (AV)</sub>	Tc=53°C	20	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	150	Α

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@20A, Pulse, T <sub>J</sub> = 25°C	0.99	1.51	V
	V <sub>F2</sub>	@20A, Pulse, T <sub>J</sub> = 150°C	-	1.24	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C	0.4	15	μA
	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125°C	283	500	μA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	31	45	ns

Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



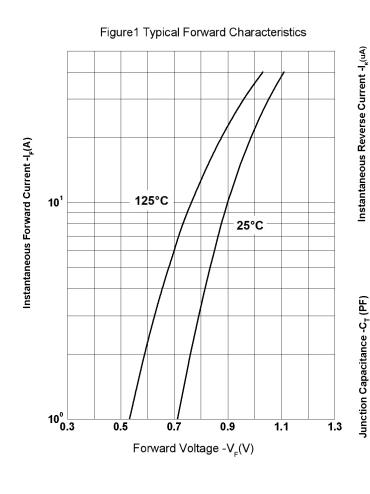


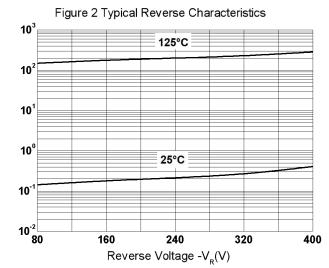


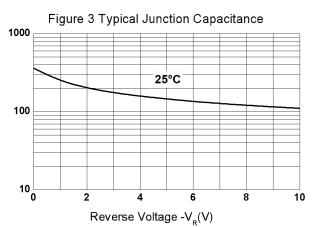
## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	4	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	ITO-220AC			

# **Ratings and Characteristics Curves**







<sup>•</sup> China - Germany - Korea - Singapore - United States •

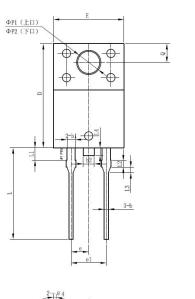
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •

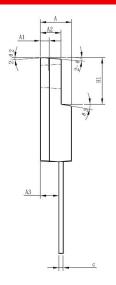






### **Mechanical Dimensions ITO-220AC**

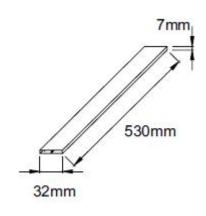




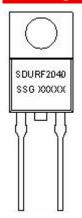


SYMBOL	Millimeters			
STIVIBUL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
С	0.55	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е	-	2.55	-	
e1	_	5.10	-	
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
L4	-	1.10	1.50	
<b>ФР1</b> (上□)	3.30	3.50	3.70	
<b>ΦP2</b> (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

## **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type F = Package type 20 = Forward Current (20A) 40 = Reverse Voltage (400V) SSG = SSG

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
SDURF2040	ITO-220AC (Pb-Free)	50 pcs/ tube	

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